TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOS V)

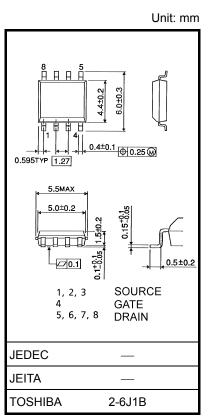
TPC8122

Lithium Ion Battery Applications Notebook PC Applications

- Small footprint due to small and thin package
- Low drain-source ON resistance: R_{DS} (ON) = 6.3 m Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 30S$ (typ.)
- Low leakage current: $I_{DSS} = -10 \mu A (max) (V_{DS} = -30 V)$
- Enhancement mode: V_{th} = -0.8 to -2.0 V (V_{DS} = -10 V, I_D = -1 mA)

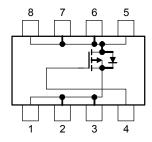
Maximum Ratings (Ta = 25°C)

| Characteri | stics | Symbol | Rating | Unit | |
|------------------------------|-----------------------------|------------------|------------|------|--|
| Drain-source voltage | | V _{DSS} | -30 | V | |
| Drain-gate voltage (R | _{GS} = 20 kΩ) | V _{DGR} | -30 | V | |
| Gate-source voltage | | V _{GSS} | ±20 | V | |
| Drain current | DC (Note 1) | I _D | -12 | A | |
| | Pulse (Note 1) | I _{DP} | -48 | | |
| Drain power dissipatio | n (t = 10 s) (Note 2a) | PD | 1.9 | W | |
| Drain power dissipatio | n (t = 10 s) (Note 2b) | PD | 1.0 | W | |
| Single pulse avalanch | e energy (Note 3) | E _{AS} | 93 | mJ | |
| Avalanche current | | I _{AR} | -12 | А | |
| Repetitive avalanche e (N | energy lote 2a) (Note 4) | E _{AR} | 0.030 | mJ | |
| Channel temperature | | T _{ch} | 150 | °C | |
| Storage temperature r | ange | T _{stg} | –55 to 150 | °C | |



Weight: 0.080 g (typ.)

Circuit Configuration



Note: Note 1, Note 2, Note 3 and Note 4: See the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

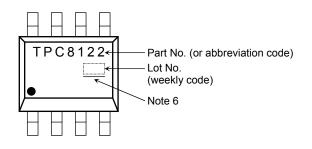
This transistor is an electrostatic-sensitive device. Please handle with caution.

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Thermal Characteristics

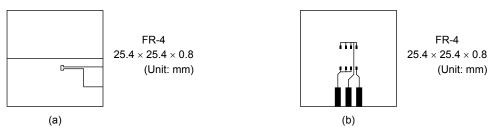
| Characteristics | Symbol | Max | Unit |
|--|------------------------|------|------|
| Thermal resistance, channel to ambient (t = 10 s) (Note 2a) | R _{th (ch-a)} | 65.8 | °C/W |
| Thermal resistance, channel to ambient (t = 10 s) (Note 2b) | R _{th (ch-a)} | 125 | °C/W |

Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)

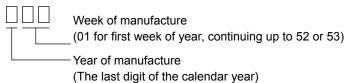


Note 3: $V_{DD} = -24 V$, $T_{ch} = 25^{\circ}C$ (initial), $L = 500 \mu H$, $R_G = 25 \Omega$, $I_{AR} = -12 A$

Note 4: Repetitive rating; pulse width limited by maximum channel temperature

Note 5: • on the lower left of the marking indicates Pin 1.

* Weekly code: (Three digits)



Note 6: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

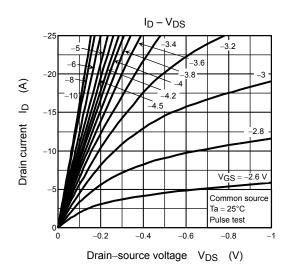
Electrical Characteristics (Ta = 25°C)

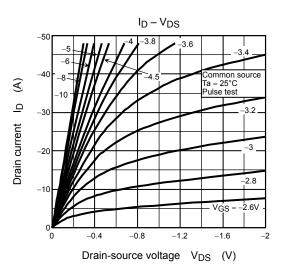
| Cha | racteristics | Symbol | Test Condition | Min Typ. Max | | Max | Unit |
|--|---|--|---|--------------|------|------|--------|
| Gate leakage curre | ent | I _{GSS} | $V_{GS}=\pm 20~V,~V_{DS}=0~V$ | _ | | ±100 | nA |
| Drain cut-OFF cur | rent | I _{DSS} | $V_{DS} = -30$ V, $V_{GS} = 0$ V | _ | | -10 | μA |
| Drain-source brea | kdown voltage | V (BR) DSS | $I_D = -10$ mA, $V_{GS} = 0$ V | -30 | | _ | V |
| Drain-source breakdown voltage | | V (BR) DSX | $I_D = -10$ mA, $V_{GS} = 20$ V | -13 | | _ | V |
| Gate threshold vol | e threshold voltage n-source ON resistance | | $V_{DS} = -10 \text{ V}, \text{ I}_{D} = -1 \text{ mA}$ | -0.8 | _ | -2.0 | V |
| Drain source ON registeres | | Deserver | $V_{GS} = -4 \text{ V}, \text{ I}_D = -6 \text{ A}$ | _ | 11.5 | 16.5 | mΩ |
| Drain-source ON I | esistance | INDS (ON) | $V_{GS} = -10 \text{ V}, \text{ I}_{D} = -6 \text{ A}$ | _ | 6.3 | 8 | 1115.2 |
| Forward transfer admittance | | Y _{fs} | $V_{DS} = -10 \text{ V}, \text{ I}_{D} = -6 \text{ A}$ | 15 | 30 | — | S |
| Input capacitance | | C _{iss} | V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz | _ | 2450 | — | pF |
| Reverse transfer capacitance | | C _{rss} | | _ | 530 | — | |
| Output capacitance | | C _{oss} | | _ | 740 | — | |
| | Rise time | tr | $V_{CS} = \begin{bmatrix} 0 & V \\ V_{CS} \end{bmatrix} \begin{bmatrix} I_D = -6 & A \end{bmatrix}$ | — | 12 | _ | |
| Switching time | Turn-ON time | $\begin{array}{c c c c c c c c c c c c c c c c c c c $ | _ | | | | |
| Switching time | Fall time | t _f | $V_{DD} \approx -15 \text{ V}$ | _ | 150 | _ | • ns |
| | Turn-OFF time | t _{off} | | _ | 360 | _ | |
| Total gate charge (gate-source plus gate-drain) | | Qg | Vpp ≈ -24 V Vcs = -10 V | | 62 | | |
| Gate-source charge 1 | | Q _{gs1} | | _ | 10 | | nC |
| Gate-drain ("miller") charge | | Q _{gd} | | _ | 19 | | |

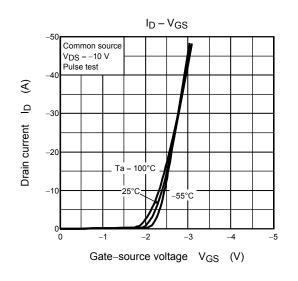
Source-Drain Ratings and Characteristics (Ta = 25°C)

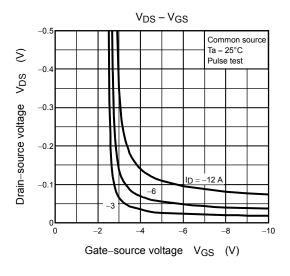
| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit | |
|-------------------------|-------|------------------|--|-----|------|-----|------|---|
| Drain reverse current | Pulse | (Note 1) | I _{DRP} | — | _ | _ | -48 | А |
| Forward voltage (diode) | | V _{DSF} | $I_{DR} = -12 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$ | | _ | 1.2 | V | |

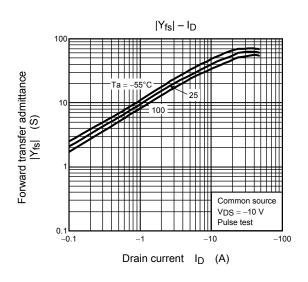
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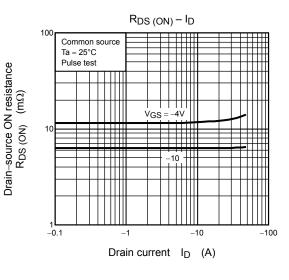




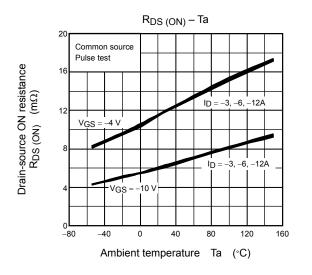


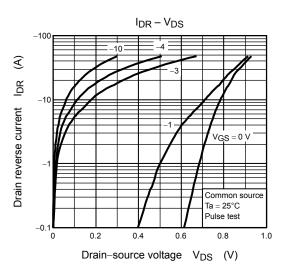


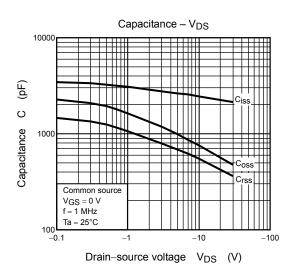


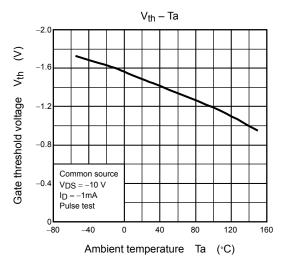


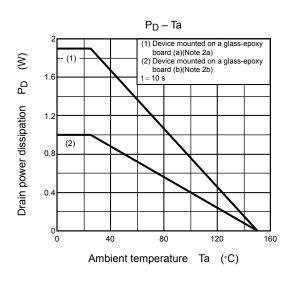
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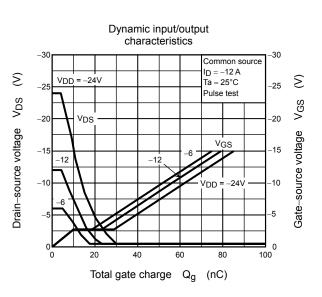


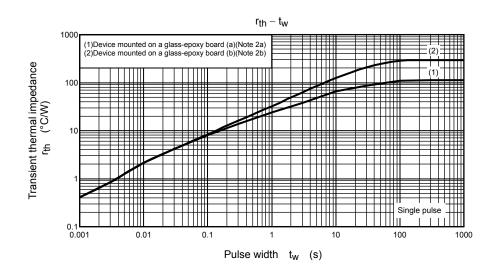


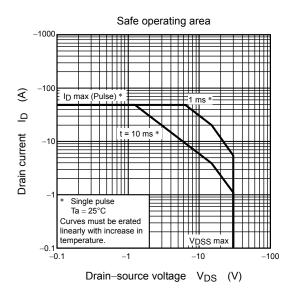












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